

# Exp.8: Transistor circuits

## Part 1: Transistor input characteristic

### 1-Objectives:

- To measure the base current ( $I_B$ ) as function of base-to-emitter voltage ( $V_{BE}$ ), keeping emitter-to-collector voltage ( $V_{CE}$ ) be constant.

### 2-Circuit elements:

- Power supply unit
- Fixed Resistor 1 k $\Omega$
- Potentiometer 1 k $\Omega$
- Transistor BD130, NPN,
- Ammeter
- Set of connecting leads

### 3-Circuit Diagram :

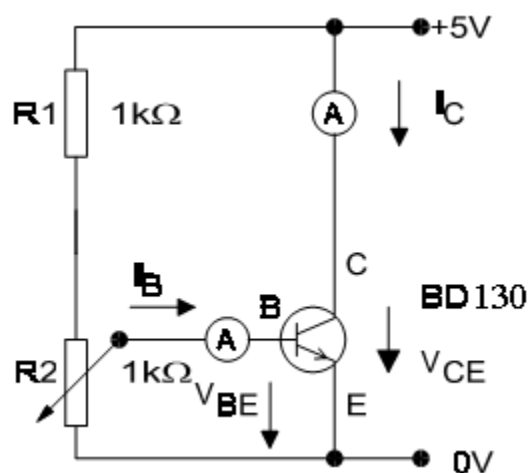


Fig. 1

#### **4-Procedure:**

- Connect the circuit as shown in the figure 1.
- Change the voltage  $V_{BE}$  by means of potentiometer and record the base current  $I_B$  values.
- Plot a graph between  $V_{BE}$  and  $I_B$ .
- Calculate the ratio of input voltage to input current for three different base currents from Tab. 1.
- a)  $I_B = 0.4 \text{ mA} \rightarrow R = \quad \Omega$
- b)  $I_B = 1.3 \text{ mA} \rightarrow R = \quad \Omega$
- c)  $I_B = 13 \text{ mA} \rightarrow R = \quad \Omega$
- Choose the operating point  $Q=( I_B , V_{BE} )$ , in the rise up region. Calculate the dynamic base resistance

(Draw tangents to the operating points)

$V_{BE}(\text{volt})$	0	0.1	0.3	0.5	0.6	0.65	0.7	0.75	0.8
$I_B(\text{mA})$									

Table 1

## Part 2: Control characteristic with current amplification

### **1-Objectives:**

- To measure how the collector current ( $I_C$ ) changes with base current ( $I_B$ ) when the collector-to-emitter voltage ( $V_{CE}$ ) is kept constant.
- To determine the current gain factor ( $\beta$ ) of a common emitter configuration circuit.

### **2-Circuit elements:**

- Power supply unit
- Fixed Resistor 1 k $\Omega$
- Potentiometer 1 k $\Omega$
- Transistor BD130, NPN,
- Ammeter
- Set of connecting leads

### 3-Circuit Diagram

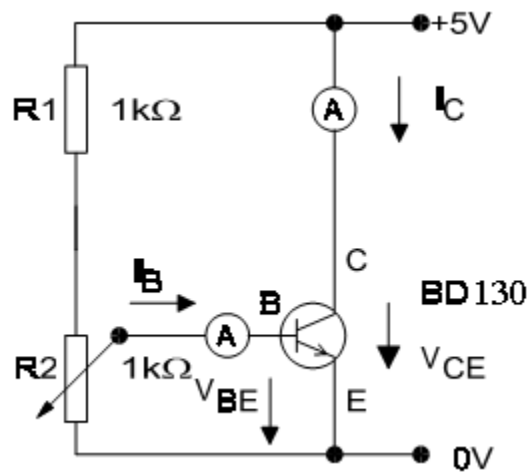


Fig. 2

### 4-Procedure:

- Connect the circuit as shown in the figure 2.
- Change the base current  $I_B$  by means of the potentiometer and record the collector current  $I_C$ .
- Determine the value ( $\beta$ ) for common emitter configuration.
- Plot a graph between  $I_B$  and  $I_C$ .

$\frac{I_B}{\text{mA}}$	$\frac{I_C}{\text{mA}}$	$\beta$
0.01		
0.02		
0.05		
0.08		
0.10		
0.20		
0.30		
0.50		

## Part 3: Transistor output characteristic

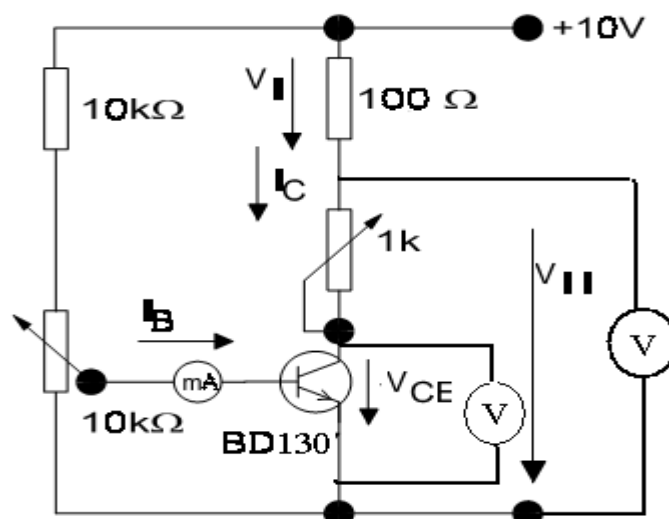
### 1-Objectives:

- Measurement methods for determining the relation between  $V_{CE}$  and  $I_C$
- Recording parameters in tables
- Representing the parameters in the output characteristic field

### 2-Circuit elements:

- Power supply unit
- Resistor  $100\ \Omega$
- Resistor  $10\ \text{k}\Omega$
- Potentiometer  $1\ \text{k}\Omega$
- Potentiometer  $10\ \text{k}\Omega$
- Transistor BD130
- 2 Multimeter
- Set of connecting leads

### 3-Circuit Diagram



### **4-Procedure:**

- 1) Connect the circuit as shown in the circuit diagram.
- 2) Set the voltages  $V_{CE}$  given in Tab. 1 using the collector potentiometer (1 k $\Omega$ ),
- 3) Measure the corresponding value VII
- 4) Calculate VI in each case (  $VI = 10V - VII$  )
- 5) Calculate the corresponding collector currents  $I_C$  ( $I_C = VI / R$  ;  $R = 100\Omega$ )
- 6) Repeat the procedure for the base currents 200  $\mu A$ , 300  $\mu A$ , 400  $\mu A$ , and 500  $\mu A$ .

$V_{CE}$ [V]	$I_B = 100 \mu A$		$I_B = 200 \mu A$		$I_B = 300 \mu A$		$I_B = 400 \mu A$		$I_B = 500 \mu A$	
	VI [V]	IC [mA]	VI [V]	IC [mA]	VI [V]	IC [mA]	VI [V]	IC [mA]	VI [V]	IC [mA]
0.2										
0.5										
1.0										
2.0										
4.0										
6.0										
8.0										

Tab. 2

- 7) Draw the characteristics from the values recorded in Tables 2.